



DMN3006SCA6

Product Summary

BV _{SSS}	R _{SS(ON) Typ}	I _{S Max} T _A = +25°C
	4.8mΩ @ V _{GS} = 8V	13.0A
30V	6.3mΩ @ V _{GS} = 4.5V	11.5A

Description

This new generation MOSFET is designed to minimize on-state resistance ($R_{SS(ON)}$) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

Battery Management

ESD PROTECTED

- Load Switch
- Battery Protection

X4-DSN3519-6 6 5 4 ()() C) 1 2 3 Top View 1. Gate 1 2. Source 1 3. Drain 4. Drain 5. Source 2 6. Gate 2

Features

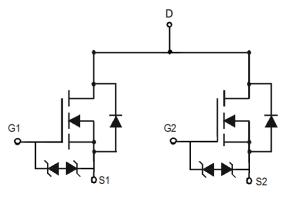
- CSP with Footprint 3.5mm × 1.9mm
- Height = 0.11mm for Low Profile
- ESD Protection of Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

N-CHANNEL ENHANCEMENT MODE MOSFET

• Halogen- and Antimony-Free. "Green" Device (Note 3)

Mechanical Data

- Case: X4-DSN3519-6
- Terminal Connections: See Diagram Below
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu or NiAu. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.0012 grams (Approximate)



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN3006SCA6-7	X4-DSN3519-6	3000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

	ΜE
•	ΥM

 $\begin{array}{l} \mathsf{ME} = \mathsf{Product Type Marking Code} \\ \mathsf{YM} = \mathsf{Date Code Marking} \\ \mathsf{Y or } \overline{\mathsf{Y}} = \mathsf{Year} \ (\mathsf{ex: H} = 2020) \\ \mathsf{M or } \overline{\mathsf{M}} = \mathsf{Month} \ (\mathsf{ex: 9} = \mathsf{September}) \end{array}$

Date Code Ke	ey .											
Year	2020	2021	20)22	2023	2024	l I	2025	2026	202	27	2028
Code	Н			J	K	L		М	Ν	C)	Р
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Source-Source Voltage	V _{SSS}	30	V		
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Source Current (Note 5) $V_{GS} = 8V$	Steady State	T _A = +25°C T _A = +70°C	I _S	13.0 10.5	А
Continuous Source Current (Note 5) V_{GS} = 4.5V	Steady State	T _A = +25°C T _A = +70°C	I _S	11.5 9.0	А
Pulsed Source Current (Note 6)	I _{SM}	80	А		

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 7)	PD	0.8	W
Thermal Resistance, Junction to Ambient @ $T_A = +25^{\circ}C$ (Note 7)	R _{θJA}	162	°C/W
Power Dissipation (Note 5)	PD	1.8	W
Thermal Resistance, Junction to Ambient @ $T_A = +25^{\circ}C$ (Note 5)	R _{0JA}	68	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	С

Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Source-Source Breakdown Voltage	BV _{SSS}	30	—	—	V	$V_{GS} = 0V, I_S = 1mA$	
Zero Gate Voltage Drain Current T _J = +25°C	I _{SSS}	_	_	1	μA	$V_{SS} = 24V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}		—	±10	μA	$V_{GS} = \pm 20V, V_{SS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	1.3	—	2.2	V	$Vss = 10V, I_S = 1mA$	
		2.5	4.6	5.5		$V_{GS} = 10V, I_{S} = 5A$	
Static Source-Source On-Resistance	R _{SS(ON)}	2.7	4.8	7.2	mΩ	$V_{GS} = 8V, I_{S} = 5A$	
	. ,	3.0	6.3	9.0		$V_{GS} = 4.5V, I_{S} = 5A$	
Diode Forward Voltage	V _{SS}	—	0.95	1.2	V	$V_{GS} = 0V, I_{S} = 5A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}	—	2235	—			
Output Capacitance	Coss	_	414	_	pF	V _{SS} = 15V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	—	274	_			
Total Gate Charge	Qq	_	17.7	_			
Gate-Source Charge	Q _{gs}	—	4.9	_	nC	$V_{SS} = 15V, V_{GS} = 4.5V,$	
Gate-Drain Charge	Q _{gd}	—	6.1	_	nc	$I_{\rm S} = 5A$	
Gate Charge at V _{TH}	Q _{g(TH)}	_	3.0	_			
Turn-On Delay Time	t _{D(ON)}	—	5.6	_			
Turn-On Rise Time	t _R	—	8.7	_	20	V _{SS} = 15V, V _{GS} = 10V,	
Turn-Off Delay Time	t _{D(OFF)}		41.6	_	ns	$I_{\rm S} = 5 {\rm A}$	
Turn-Off Fall Time	t _F		20.9	—			

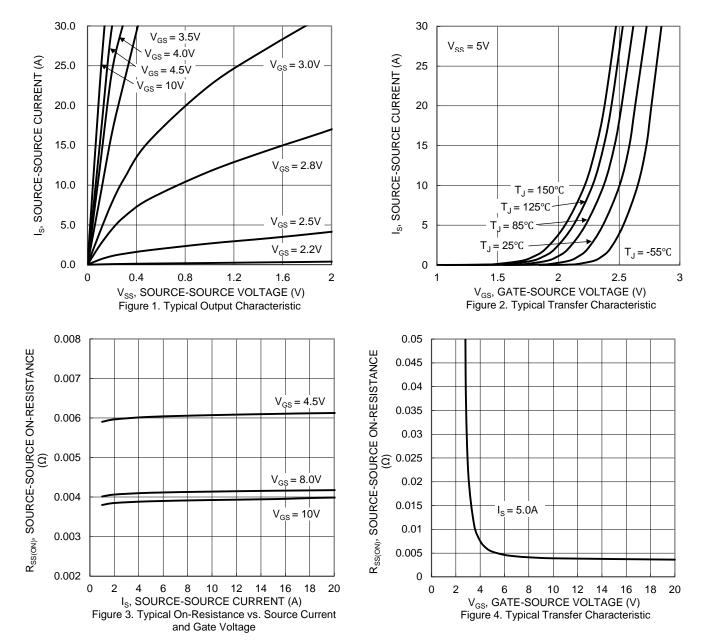
Notes:

Device mounted on FR-4 material with 1inch² (6.45cm²), 2oz. (0.071mm thick) Cu.
Repetitive rating, pulse width limited by junction temperature.
Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.
Short duration pulse test used to minimize self-heating effect.
Occurrented by device the subject to product the production temperature.

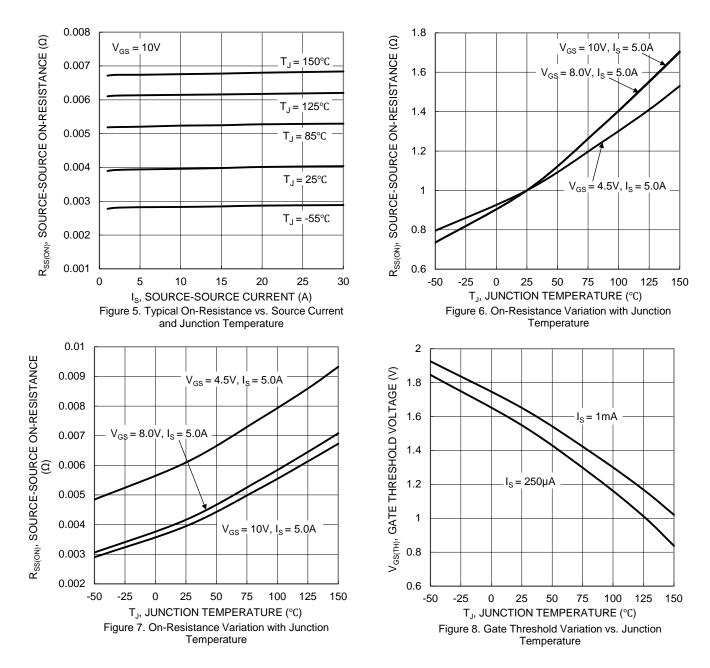
9. Guaranteed by design. Not subject to production testing.



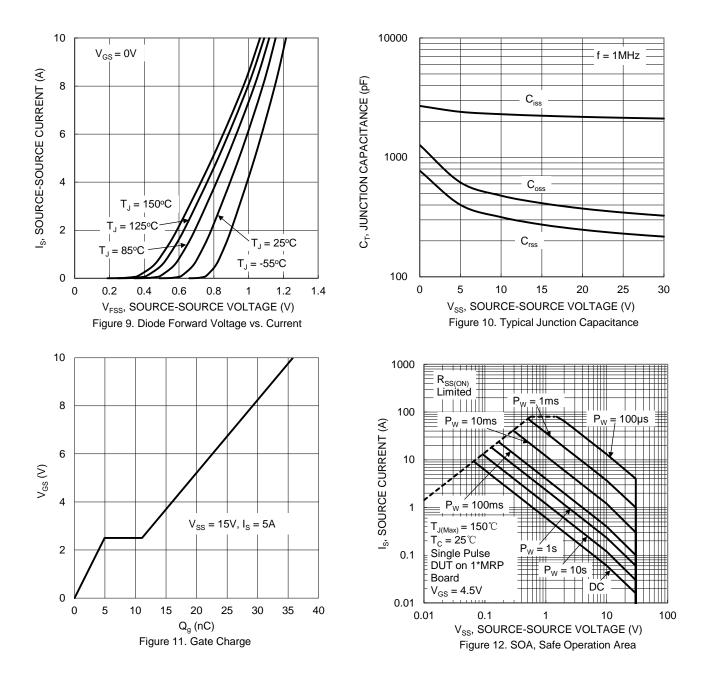
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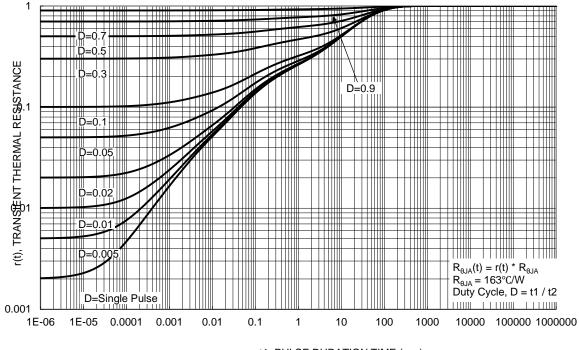










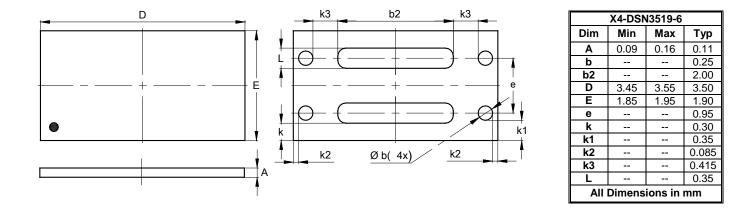


t1, PULSE DURATION TIME (sec) Figure 13. Transient Thermal Resistance



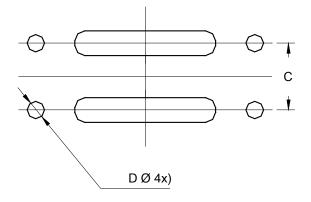
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)				
С	0.95				
Х	0.25				



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